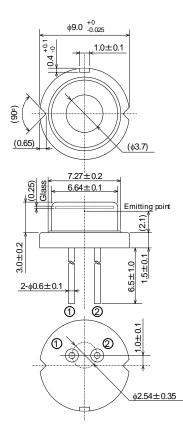


HL65213HD

659nm/1.2W (CW)/1.5W (Pulse) AlGaInP Laser Diode

Outline



(Unit: mm)

Features

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- Single emitter
- Optical output power: 1.2W (CW)
 - 1.5W (Pulse)
- Wavelength: 659nm Typ.
- High wall plug efficiency: 39% Typ.
- High heat dissipation ϕ 9mm CAN package
- Multi transverse mode
- TE mode oscillation

Internal Circuit



Application

- Medical
- Laser module
- Sensing
- Light source of optical equipments

Absolute Maximum Ratings (Tc=25°C)

Item	Symbol	Ratings	Unit
Optical output power Note3)	Po	1.2	W
Pulse optical output power Note2) Note3)	Po(Pulse)	1.5	W
LD reverse voltage	VR(LD)	2	V
Operating temperature Note1) Note3)	Topr	-10 ~ +45	°C
Storage temperature	Tstg	-40 ~ +85	°C

Note1) Operating temperature is defined by Case temperature "Tc". High increase in temperature of LD chip itself is expected during operation due to high current density. Thus, without proper heat dissipation, it is observed that no specific output power is achieved or it results to LD degradation. It is advised that sufficient measure of heat dissipation should be taken so that LD's maximum operating temperature is not exceeded during actual operation.

Note2) Pulse condition: Pulse frequency≥50Hz, duty=33%

Note3) The relation of optical output power vs operating temperature is based on Fig.1.

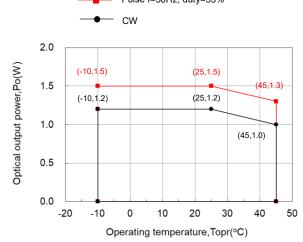


Fig.1 The relation of optical output power vs operating temperature

Optical and Electrical Characteristics (Tc=25°C)

Parameter	Symbol	Min	Тур	Мах	Unit	Test Condition
Threshold current	lth	-	450	600	mA	-
Operating current	Іор	-	1350	1600	mA	Po=1.2W
Operating voltage	Vop	-	2.3	2.7	V	Po=1.2W
Beam divergence ^{Note4)} Parallel to the junction	θ//	3	10	20	0	Po=1.2W, FWHM
Beam divergence ^{Note4)} Perpendicular to the junction	θ⊥	23	33	43	o	Po=1.2W, FWHM
Lasing Wavelength	λρ	654	659	664	nm	Po=1.2W

Note4) Designed value

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